NSN 5961-00-465-8319

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-465-8319 **Inclosure Material:** Metal **Overall Length:** 2.500 inches **Overall Diameter:** 1.031 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.062 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1000.0 breakover voltage, dc **Current Rating Per Characteristic:** 500.00 milliamperes forward current, total rms peak **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector outside diameter **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator: Terminal Type And Quantity:** 1 threaded stud and 3 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

Fiig: A110a0